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Chip Monolithic Ceramic Capacitors



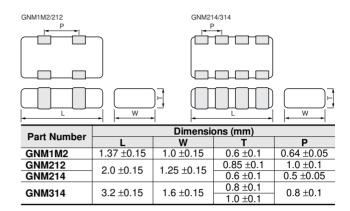
Capacitor Arrays

■ Features

- 1. High density mounting due to mounting space saving
- 2. Mounting cost saving

■ Applications

General electronic equipment



Temperature Compensating Type

Part Number	GI	NM31			
LxW	3.2	2x1.6			
тс	C0G (5C)				
Rated Volt.	100 (2A)	50 (1H)			
Capacitance (Capacitance par	t numbering code) and T (mm) Dimension (T Dime	nsion part numbering code)			
10pF(100)	0.8(4)	0.8(4)			
11pF(110)	0.8(4)	0.8(4)			
12pF(120)	0.8(4)	0.8(4)			
13pF(130)	0.8(4)	0.8(4)			
15pF(150)	0.8(4)	0.8(4)			
16pF(160)	0.8(4)	0.8(4)			
18pF(180)	0.8(4)	0.8(4)			
20pF(200)	0.8(4)	0.8(4)			
22pF(220)	0.8(4)	0.8(4)			
24pF(240)	0.8(4)	0.8(4)			
27pF(270)	0.8(4)	0.8(4)			
30pF(300)	0.8(4)	0.8(4)			
33pF(330)	0.8(4)	0.8(4)			
36pF(360)	0.8(4)	0.8(4)			
39pF(390)	0.8(4)	0.8(4)			
43pF(430)	0.8(4)	0.8(4)			
47pF(470)	0.8(4)	0.8(4)			
51pF(510)	0.8(4)	0.8(4)			
56pF(560)	0.8(4)	0.8(4)			
62pF(620)	0.8(4)	0.8(4)			
68pF(680)	0.8(4)	0.8(4)			
75pF(750)	0.8(4)	0.8(4)			
82pF(820)	0.8(4)	0.8(4)			
91pF(910)	0.8(4)	0.8(4)			
100pF(101)	0.8(4)	0.8(4)			
110pF(111)	0.8(4)	0.8(4)			
120pF(121)	0.8(4)	0.8(4)			
130pF(131)	0.8(4)	0.8(4)			
150pF(151)	0.8(4)	0.8(4)			
160pF(161)		0.8(4)			
180pF(181)		0.8(4)			

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Part Number	GNM31					
LxW	3.2x1.6					
тс	C0G (5C)					
Rated Volt.	100 (2A) 50 (1H)					
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)				
200pF(201)		0.8(4)				
220pF(221)		0.8(4)				
240pF(241)		0.8(4)				
270pF(271)		0.8(4)				
300pF(301)		0.8(4)				
330pF(331)		0.8(4)				
360pF(361)		0.8(4)				

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM1 Series

Part Number	GNM1M						
LxW	1.37x1.00						
тс	X7R (R7)						
Rated Volt.	16 (1C)	10 (1A)					
Capacitance (Ca	Capacitance (Capacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)						
22000pF(223)	0.6(2)						
47000pF(473)	0.6(2)						
0.10μF(104)		0.6(2)					

The part numbering code is shown in each (). The (2) code in T(mm) means number of elements (two).

Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM2 Series

Part Number	GNM21
LxW	2.0x1.25
тс	X7R (R7)
Rated Volt.	50 (1H)
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)
1000pF(102)	0.6(4)
10000pF(103)	0.6(4)

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM3 Series

Part Number	GNM31								
LxW	3.2x1.6								
тс	X7R (R7)							Y5V (F5)	
Rated Volt.	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 50 (2A) (1H)		16 (1C)		
Capacitance (Ca	apacitance (Capacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)								
220pF(221)	0.8(4)								

Continued from the preceding page.

Part Number				GNM31					
LxW	3.2x1.6								
тс	X7R (R7)				Y5V (F5)				
Rated Volt.	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	16 (1C)		
Capacitance (Capa	citance part nui	mbering code) and	T (mm) Dimension	(T Dimension part	numbering code)				
270pF(271)	0.8(4)								
330pF(331)	0.8(4)								
390pF(391)	0.8(4)	0.8(4)							
470pF(471)	0.8(4)	0.8(4)							
560pF(561)	0.8(4)	0.8(4)							
680pF(681)	0.8(4)	0.8(4)							
820pF(821)	0.8(4)	0.8(4)							
1000pF(102)	0.8(4)	0.8(4)							
1200pF(122)	0.8(4)	0.8(4)							
1500pF(152)	0.8(4)	0.8(4)							
1800pF(182)	0.8(4)	0.8(4)							
2200pF(222)	0.8(4)	0.8(4)			0.8(4)				
2700pF(272)	0.8(4)	0.8(4)							
3300pF(332)	0.8(4)	0.8(4)			0.8(4)				
3900pF(392)	0.8(4)	0.8(4)							
4700pF(472)	0.8(4)	0.8(4)			0.8(4)				
5600pF(562)		0.8(4)							
6800pF(682)		0.8(4)							
8200pF(822)		0.8(4)							
10000pF(103)		0.8(4)							
12000pF(123)		0.8(4)							
15000pF(153)		0.8(4)							
18000pF(183)			0.8(4)						
22000pF(223)				0.8(4)		0.8(4)			
27000pF(273)				0.8(4)					
33000pF(333)				0.8(4)		0.8(4)			
39000pF(393)				0.8(4)					
47000pF(473)				1.0(4)		0.8(4)			
68000pF(683)				1.0(4)			0.8(4)		
0.10μF(104)				1.0(4)			0.8(4)		
0.15μF(154)							0.8(4)		

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four).

Dimensions are shown in mm and Rated Voltage in Vdc.

Specifications and Test Methods

				Specifications				
No.	lte	em	Temperature Compensating Type	High Dielectric Type		Test Method		
1	Operating Temperati	ıre Range	5C : −55°C to +125°C	R7 : −55°C to +125°C F5 : −30°C to +85°C				
2	Rated Vo	ltage	See the previous pages.		The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{p.p} or V ^{o.p} , whichever is larger, should be maintained within the rated voltage range.			
3	Appearar	nce	No defects or abnormaliti	es	Visual inspection			
4	Dimensio	n	Within the specified dime	nsions	Using calipers			
5	Dielectric	Strength	No defects or abnormaliti	es	No failure should be observed when 300% of the rated vo (5C) or 250% of the rated voltage (R7, F5) is applied between the terminations for 1 to 5 seconds, provided the charge/d charge current is less than 50mA.			ed between
6	Insulation Resistance More than $10,000M\Omega$ or $(Whichever is smaller)$			500Ω • F		ance should be meas ne rated voltage at 25 of charging.		
7	Capacita	nce	Within the specified tolera 30pF min. : Q≥1000	ance	The capacitance/Q/I quency and voltage	D.F. should be measu shown in the table.	ured at 25	℃ at the fre-
8	Q/Dissipation Factor (D.F.)		30pF max. : Q≥400+20C C : Nominal Capacitance	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	Frequency Voltage	1±0.1MHz 0.5 to 5Vr.m.s.	1±0	7, F5 0.1kHz .2Vr.m.s.
		Capacitance Change	(pF) Within the specified tolerance (Table A)	Char. Temp. Reference Range Cap. Change R7 -55 to +125℃ 25℃ Within±15% F5 -30 to +85℃ 25℃ Within±62%	each specified temp (1) Temperature Cor The temperature	•	ned using	ı the
	Capacitance	Temperature Coefficient	Within the specified tolerance (Table A)		When cycling the through 5, the ca tolerance for the	temperature sequen pacitance should be temperature coefficie	tially from within the	step1 specified
					differences between	A. drift is calculated by centhe maximum and 3 and 5 by the capace	l minimum	n measured
9	Temperature Characteristics				Step	Tempera		
	Onuracionolico				1	25±		
		Capacitance	Within $\pm 0.2\%$ or ± 0.05 pF		2	-55±3 (for 5C/ R7), -30±3	(for F5)
		Drift	(Whichever is larger)		3	25±	<u>+2</u>	
					4	125±3 (for 5C/F	R7), 85±3	(F5)
					above 25°C value	onstant Type pacitance change colover the temperature railing the specified rail	mpared w	
			No removal of the termina	ations or other defect should occur.		to the test jig (glass		
10	Adhesive	Strength		b	with the test jig for 1 The soldering should reflow method and s	ic solder. Then apply 0±1 sec. If be done either with hould be conducted and free of defects so	an iron or with care :	using the
10	of Termin				Туре	a b	С	d
					GNM1M GNM21	0.5 — 0.4 1.6	0.32	0.32
				<u> </u>	GNM21 GNM31	0.4 1.6 0.8 2.5	0.25	0.5
				Solder resist Copper foil		Fig. 1		(in mm)

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Specifications and Test Methods

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	- '			Specifications				
No.	lte	em	Temperature Compensating Type	High Dielectric Type	Test Method			
		Appearance	No defects or abnormaliti	es	Solder the capacitor to the test jig (glass epoxy board) in the			
		Capacitance	Within the specified tolera	ance	same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion			
11	Vibration Resistance	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).			
	<u> </u>		No cracking or marking d	efects should occur.	Solder the capacitor on the test jig (glass epoxy board) shown			
			•GNM□□4	•GNM□□2	in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3 for 5±1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.			
12	Deflection	1	5.0 100		speed : 1.0mm/sec. Pressurize R230 Flexure : ≦1 Capacitance meter			
			GNM21 2.0±0	0.05 0.7±0.05 0.3±0.05 0.2±0.05	45 45 (in mm)			
			GNM31 2.5±0		Fig. 3			
			(in mm) Fig. 2		t=0.8mm (GNM21), 1.6mm (GNM31)			
13	Solderability of Termination		75% of the terminations are to be soldered evenly and continuously.		Immerse the capacitor in a solution of ethanol (JIS-K-8101) an rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat a 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5℃.			
			The measured and obser specifications in the follow	ved characteristics should satisfy the wing table.				
		Appearance	No marking defects		Preheat the capacitor at 120 to 150℃ for 1 minute. Immerse the			
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	capacitor in a eutectic solder solution at 270±5°C for 10±0.5 seconds. Let sit at room temperature for 24±2 hours (tempera-			
14	Resistance to Soldering		30pF min. : Q≥1000 30pF max. : Q≥400+20C	Char. 25V min. 16V 10V	ture compensating type) or 48±4 hours (high dielectric constant type), then measure.			
	Heat	Q/D.F.	C : Nominal Capacitance (pF)	R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	• Initial measurement for high dielectric constant type Perform a heat treatment at 150 ± 0 °C for one hour and then			
		I.R.		0.000 • F (Whichever is smaller)	let sit for 48±4 hours at room temperature. Perform the initial measurement.			
		Dielectric Strength	No failure	(
			The measured and obser	ved characteristics should satisfy the wing table.	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles			
		Appearance	No marking defects	g televici	according to the four heat treatments listed in the following			
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	table. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure			
	Temperature		30pF min. : Q≧1000		Step 1 2 3 4			
15	Cycle	Q/D.F.	30pF max. : Q≥400+20C C : Nominal Capacitance	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	Temp. (°C) Min. Operating Temp. ±3 Temp. Time (min.) 30±3 2 to 3 30±3 2 to 3			
			(pF)		Initial measurement for high dielectric constant type			
		I.R.	More than 10,000MΩ or	500Ω • F (Whichever is smaller)	Perform a heat treatment at 150 ± 0 ℃ for one hour and then			
		Dielectric Strength	No failure		let sit for 48±4 hours at room temperature. Perform the initial measurement.			

Continued on the following page.





Specifications and Test Methods

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				Specifications							
No.	lt€	em	Temperature Compensating Type	High Dielectric Type	Test Method						
		The measured and observed of specifications in the following		rved characteristics should satisfy the wing table.							
		Appearance	No marking defects								
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Let the capacitor sit at 40±2°C and 90 to 95% humidity for						
16	Humidity Steady State	Q/D.F.	30pF and over : Q≥350 10pF and over, 30pF and below : Q≥275+5C/2 10pF and below : Q≥200+10C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.						
		I.R.	More than 1,000MΩ or 5	$0\Omega \cdot F$ (Whichever is smaller)							
		Dielectric Strength	No failure								
			The measured and obserspecifications in the follow	rved characteristics should satisfy the wing table.							
		Appearance	No marking defects								
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply the rated voltage at 40±2°c and 90 to 95% humidity for						
17	Humidity Load	Q/D.F.	30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.						
		I.R.	More than 500MΩ or 250	2 • F (Whichever is smaller)							
		Dielectric Strength	No failure								
			The measured and obserspecifications in the follow	rved characteristics should satisfy the wing table.							
		Appearance	No marking defects								
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply 200% of the rated voltage for 1000±12 hours at the						
18	High Temperature Load	Q/D.F.	30pF and over : Q≥350 10pF and over, 30pF and below :	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement.						
		I.R.	More than 1,000M Ω or 5	0Ω • F (Whichever is smaller)							
		Dielectric Strength	No failure								

Table A

		Capacitance Change from 25℃ (%)					
Char.	Nominal Values (ppm/℃) Note 1	-55		-30		-10	
	(ppiii/ C) Note 1	Max.	Min.	Max.	Min.	Max.	Min.
5C	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11

Note 1 : Nominal values denote the temperature coefficient within a range of 25°C to 125°C.

